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A novel heterojunction photocatalyst, Bi₂SiO₅/g-C₃N₄: synthesis, characterization, photocatalytic activity, and mechanism†

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A new type of heterojunction photocatalyst, Bi₂SiO₅/g-C₃N₄, was prepared using a controlled hydrothermal method. The structure and morphology of the Bi₂SiO₅/g-C₃N₄ photocatalyst were characterized by XRD, HR-TEM, FE-SEM-EDS, HR-XPS, FT-IR, PL, BET, EPR, and UV-Vis-DRS. The obtained Bi₂SiO₅/g-C₃N₄ photocatalyst exhibits enhanced photocatalytic activity on the decolorization of crystal violet (CV) under visible-light irradiation. In particular, the catalytic performance illustrates the best reaction rate constant of 0.1257 h⁻¹ using Bi₂SiO₅/g-C₃N₄ as the photocatalyst, which is 5 and 3 times higher than the reaction rate constants of Bi₂SiO₅ and g-C₃N₄ as photocatalysts, respectively. This study shows that Bi₂SiO₅/g-C₃N₄ can be used to suppress the recombination of photoinduced electron-hole pairs and contribute to the enhanced photocatalytic efficiency of semiconductors in the visible light-driven catalysis. The quenching effects of different scavengers, and EPR results demonstrate that the reactive O₂^{•-} plays the major role and [•]OH, h⁺ and ¹O₂ play minor roles in CV degradation. The probable photodegradation mechanisms are proposed and discussed.

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1. Introduction

In the past decade, heterogeneous photocatalysis for environmental remediation and solar energy conversion has aroused extensive interest. For the practical applications of photocatalysis, an environmentally powerful and cheap photocatalyst is an important component.¹ As such, triphenylmethane dyes have found applications as colorants in industry and as antimicrobial agents.² However, great troubles have arisen with respect to the thyroid peroxidase-catalyzed oxidation of the triphenylmethane (triarylmethane) class of dyes because the reactions might produce various *N*-de-alkylated primary and secondary aromatic amines, with structures similar to aromatic amine carcinogens.³ The degradation of CV, a cationic triarylmethane dye, was studied using several systems that generated active species, including Bi₂WO₆,⁴ TiO₂,^{5–10} ZnO,^{11–13} SrTiO₃,¹⁴ BiOX/BiOY (X, Y = Cl, Br, I),¹⁵ Bi_xAg_yO_z,¹⁶ BaTiO₃,¹⁷ activated charcoal/Bi/ZnO,¹⁸ Ti(SO₄)₂,¹⁹ CdS/TiO₂/rGO,²⁰ CdS/ZnO,²¹ CuS/Bi₂S₃,²² bismuth silver oxide,²³ Ag/AgVO₃,²⁴ n-BiVO₄@p-MoS₂,²⁵ 2D-Ag-TiO₂,²⁶ Au/TiO₂/h-BN,²⁷ NaYF₄:Yb,Tm@TiO₂/

Ag (UC@TiO₂/Ag),²⁸ Ag@AgCl/ZnSn(OH)₆,²⁹ SiO₂@TiO₂,³⁰ Zn₃V₂O₈,³¹ Fe₃O₄@SiO₂@TiO₂@Ag,³² [(Me)₂-2,2'-bipy]₂Ag₇-I₁₁,³³ K₂Ti₈O₁₇,³⁴ In₂S₃,³⁵ and Ag/Bi₂O₃/TiO₂.³⁶

Recently, Bi-based layered structure compounds, within the Aurivillius family, such as BiOX (X = Cl, Br, I),^{37,38} Bi₂WO₆,³⁹ BiVO₄,⁴⁰ Bi₄Ti₃O₁₂,⁴¹ *etc.*, have been extensively researched as highly efficient photocatalysts due to their unique layered structures and high catalytic activities. It is thought that the Bi 6s and O 2p levels can make a largely dispersed hybridized valence band, which favors the mobility of photogenerated holes and oxidation reactions, inducing efficient separation of photogenerated electron-hole pairs and then improving photocatalytic efficiency.⁴²

In the Bi₂O₃-SiO₂ binary system, there are three compounds, Bi₁₂SiO₂₀, Bi₄Si₃O₁₂ and Bi₂SiO₅,^{43–45} where Bi₂SiO₅ is one of the newly found compounds within the Aurivillius family. It has been described as a promising material with relatively good piezoelectric and dielectric properties and nonlinear optical effects. Recently, its luminescence properties were also reported. Pure Bi₂SiO₅ crystals were prepared by a novel method involving the melt-cooling process⁴⁶ and the molten salt method in NaCl-Na₂SO₄ flux, using Bi₂O₃ and SiO₂ as starting materials.⁴⁷ Xie *et al.* also synthesized Bi₄Si₃O₁₂ by a sol-gel method using Si(OC₂H₅)₄ and Bi(NO₃)₃·5H₂O as the precursors, and acetic acid as the solvent.⁴⁸ He *et al.* prepared Bi₁₂SiO₂₀ by a chemical solution decomposition technique using Bi(NO₃)₃·5H₂O and Si(OC₂H₅)₄ as the starting materials for the degradation of Congo red.⁴⁹ Duan's group synthesized Bi₂SiO₅ by

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hydrothermal methods, and it demonstrated excellent photocatalytic abilities and good stability during rhodamine B photodegradation under visible-light irradiation.⁵⁰ Chen *et al.* showed the synthesis of Bi₂SiO₅ by a template-free hydrothermal method, and the Bi₂SiO₅ showed higher photocatalytic activity toward salicylic acid and benzene under UV-light irradiation.⁴⁵ Police *et al.* reported porous Bi₂SiO₅ by an emulsion polymerization technique, for the degradation of isoproturon.⁵¹ Bi₄Si₃O₁₂ nanofibers were also synthesized and tested for the degradation of methylene blue.⁵²

Recently, the development of visible-light-driven photocatalysts has obtained considerable attention as an alternative in wastewater treatment. An effective and simple tactic to improve the photocatalytic activity of a photocatalyst is the incorporation of a heterostructure, because heterojunctions have great potential for tuning the desired electronic properties of photocatalysts and efficiently separating the photogenerated electron-hole pairs.^{48–50} So far, heterojunctions concerning Bi₂SiO₅, such as Bi₄O₅Br₂/Bi₂₄O₃₁Br₁₀/Bi₂SiO₅, have been reported, which exhibit enhanced photocatalytic efficiency.⁵³ Therefore, it is feasible for BiOBr to be partly transformed into Bi₂SiO₅ *via* a thermodynamically favored route through the ion exchange reaction, which allows the exchange between the component ions and the incoming species,⁵⁴ and consequently, the BiOBr/Bi₂SiO₅ heterojunction can be obtained. Wan *et al.* reported excellent photocatalytic activities of Bi₂SiO₅/AgI nanoplates for acid red G and formaldehyde.⁵⁵ Liu *et al.* revealed that the photocatalytic activities of the Bi₂S₃/Bi₂SiO₅ heterojunctions were evaluated by degrading rhodamine B under visible light and UV-vis light irradiation.⁵⁶ Lei *et al.* found that Ti-modified MoO₃-Bi₂SiO₅/SiO₂ exhibits excellent catalytic performance for the epoxidation of propylene by molecular oxygen.⁵⁷

In the search for powerful and stable visible-light-driven photocatalysts, a polymeric semiconductor, graphitic carbon nitride (g-C₃N₄), has recently attracted great attention. The heptazine ring structure and high condensation degree enable the metal-free g-C₃N₄ to possess many advantages such as good physicochemical stability, as well as an appealing electronic structure combined with a medium-band gap (2.7 eV).⁵⁸ These unique properties make g-C₃N₄ a promising candidate for visible light photocatalytic applications utilizing solar energy.

Graphitic carbon nitride is a well-known π -conjugated material for the improvement of the photogenerated electron-hole pair separation. More importantly, it is profoundly resistant to temperature and chemicals due to its s-triazine ring structure and high condensation. Besides, the g-C₃N₄ sheet is a soft polymer and can therefore be used as a coating material for other compounds. Recently, BiOI/g-C₃N₄,⁵⁹ Ag₃PO₄@g-C₃N₄,⁶⁰ and Zn₂GeO₄/g-C₃N₄ (ref. 61) composites have been synthesized in order to improve the photocatalytic activity of the materials. It is expected that functionalizing g-C₃N₄ nanosheets with bismuth silicates will not only combine the advantages of both bismuth silicate and g-C₃N₄ nanosheets, but will also result in new properties. However, no work on g-C₃N₄ based on bismuth silicate photocatalysts has been reported.

To the best of our knowledge, nanocomposite semiconductors consisting of Bi₂SiO₅ and g-C₃N₄ have not yet been reported in the literature. This is the first report that Bi₂SiO₅/g-C₃N₄ heterojunctions have been prepared by a template-free hydrothermal method and characterized by FE-SEM-EDS, XRD, HR-XPS, and UV-Vis-DRS. Through the degradation of CV in aqueous solutions under visible-light irradiation, the photocatalytic activities of four Bi₂SiO₅/g-C₃N₄ composites are compared and discussed.

2. Experimental

2.1. Materials

Na₂SiO₃ and ammonium oxalate (Osaka), Bi(NO₃)₃·5H₂O, KI and urea (Katayama), CV dye (TCI), *p*-benzoquinone (Alfa Aesar), sodium azide and cetyltrimethylammonium bromide (CTAB) (Sigma-Aldrich), and isopropanol (Merck) were purchased and used without further purification. Reagent-grade sodium hydroxide, nitric acid, ammonium acetate, and HPLC-grade methanol were obtained from Merck.

2.2. Instrumentation and analytical methods

Field emission scanning electron microscopy-electron dispersive X-ray spectroscopy (FE-SEM-EDS) measurements were carried out using JEOL JSM-7401F machine at an acceleration voltage 15 kV. The Al-K α radiation was generated at 15 kV. The X-ray diffraction (XRD) patterns were recorded on a MAC Science MXP18 equipped with Cu-K α radiation, operating at 40 kV and 80 mA. The field-emission transmission electron microscopy (FE-TEM) images, selected area electron diffraction (SAED) patterns, high resolution transmission electron microscopy (HRTEM) images, and energy-dispersive X-ray spectra (EDS) were obtained using a JEOL-2010 machine with an accelerating voltage of 200 kV. Photoluminescence (PL) measurements were carried out on Hitachi F-7000. High resolution X-ray photoelectron spectroscopy (HRXPS) measurements were carried out using a ULVAC-PHI. The ultra-violet photoelectron spectroscopy (UPS) measurements were performed using a ULVAC-PHI XPS, PHI Quantera SXM. The Brunauer-Emmett-Teller (BET) specific surface areas of the samples (S_{BET}) were measured with an automated system (Micrometrics Gemini) using nitrogen gas as the adsorbate at liquid nitrogen temperature.

2.3. Synthesis of Bi₂SiO₅/g-C₃N₄

Under atmospheric conditions, the g-C₃N₄ powder was synthesized by directly calcining melamine in a muffle furnace. In a typical synthesis run, 5 g melamine was placed in a semi-closed alumina crucible with a cover. The crucible was heated to 520 °C for 4 h with a heating rate of 10 °C min⁻¹. After cooling to room temperature, g-C₃N₄ was produced in powder form.⁶² 2 mmol Bi(NO₃)₃·5H₂O and 1 mmol Na₂SiO₃ were first mixed in a 50 mL flask, followed by the addition 30 mL 4 M HNO₃. With continuous stirring, 2 M NaOH were added dropwise to adjust the pH to 13. The solution was then stirred vigorously for 30 min and transferred into a 30 mL Teflon-lined autoclave, which was

heated up to 150 °C for 24 h and then naturally cooled down to room temperature. Solution A (0.5 g g-C₃N₄ and 0.05 g CTAB followed by adding 10 mL ethylene glycerol) and solution B (0.5 g Bi₂SiO₅ followed by adding 10 mL ethylene glycerol and 0.07 g urea) were first mixed in a 50 mL flask. The solution was then stirred vigorously for 20 min and transferred into a 30 mL Teflon-lined autoclave, which was heated up to 150 °C for 4 h and then naturally cooled down to room temperature. The resulting solid precipitate was collected by filtration, washed with deionized water and methanol to remove any possible ionic species in the solid precipitate, and then dried at 60 °C overnight.

2.4. Photocatalytic experiments

The CV irradiation experiments were carried out on a stirred aqueous solution contained in a 100 mL flask; the aqueous suspension of CV (100 mL, 10 ppm) and the catalyst powder was placed in a Pyrex flask. The pH of the suspension was adjusted by adding either NaOH or HNO₃ solution. The experiments were performed in the dark in order to examine the adsorption/desorption equilibrium. 10 mg of the photocatalyst was mixed with 100 mL of CV aqueous solution with a known initial concentration, in a 100 mL flask, and the mixture was shaken in an orbital shaker (100 rpm) at a constant temperature. The mixture was centrifuged at 3000 rpm in a centrifugation machine after batch sorption experiments so that the absorbance of CV could be determined at 580 nm by means of HPLC-PDA-ESI-MS. The concentrations of the solutions were determined using the linear regression equation. Prior to the irradiation, the suspension was magnetically stirred in the dark for *ca.* 30 min to establish an adsorption/desorption equilibrium between the CV and the catalyst surface. Irradiation was carried out using 150 W Xe arc lamps; the light intensity was fixed at 31.2 W m⁻², and the reaction vessel was placed at 30 cm from the light source. At given irradiation time intervals, a 5 mL aliquot was collected and centrifuged to remove the catalyst. The supernatant was measured by HPLC-PDA-ESI-MS.

A series of quenchers was introduced to scavenge the relevant active species, in order to evaluate the effect of the active species during the photocatalytic reaction. O₂^{•-}, [•]OH, h⁺, and ¹O₂ were studied by adding 1.0 mM benzoquinone (BQ, a quencher of O₂^{•-}),⁶³ 1.0 mM isopropanol (IPA, a quencher of [•]OH),⁶⁴ 1.0 mM ammonium oxalate (AO, a quencher of h⁺),⁶⁵ and 1.0 mM sodium azide (SA, a quencher of ¹O₂),⁶⁶ respectively. The method was similar to the previous photocatalytic activity test.

3. Results and discussion

3.1. Characterization of Bi₂SiO₅/g-C₃N₄ composites

3.1.1. Phase structure. Fig. 1 shows the XRD patterns of the as-prepared samples; the patterns clearly show the existence of the Bi₂SiO₅ phase composite with g-C₃N₄. All the samples as-prepared contain the Bi₂SiO₅ phase (JCPDS 01-075-1483) and the g-C₃N₄ (JCPDS 87-1526) phase. Fig. 2(a)–(d) display that the 10 wt% Bi₂SiO₅/g-C₃N₄ samples are composed of different-sized

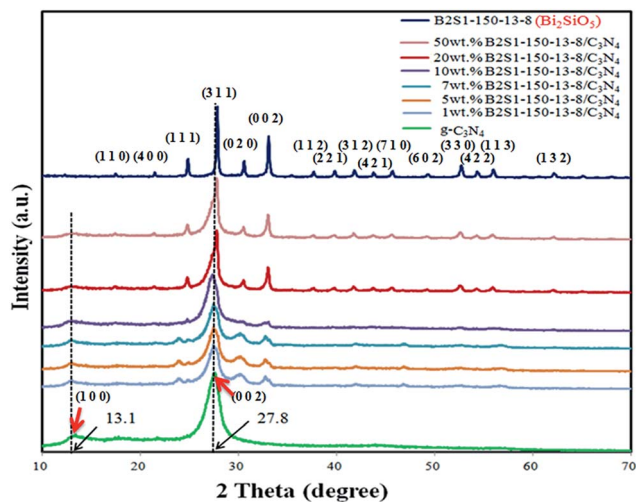


Fig. 1 XRD patterns of the as-prepared Bi₂SiO₅/g-C₃N₄ samples with different weight percentages (%), temp. = 150 °C, pH = 13, and time = 8 h.

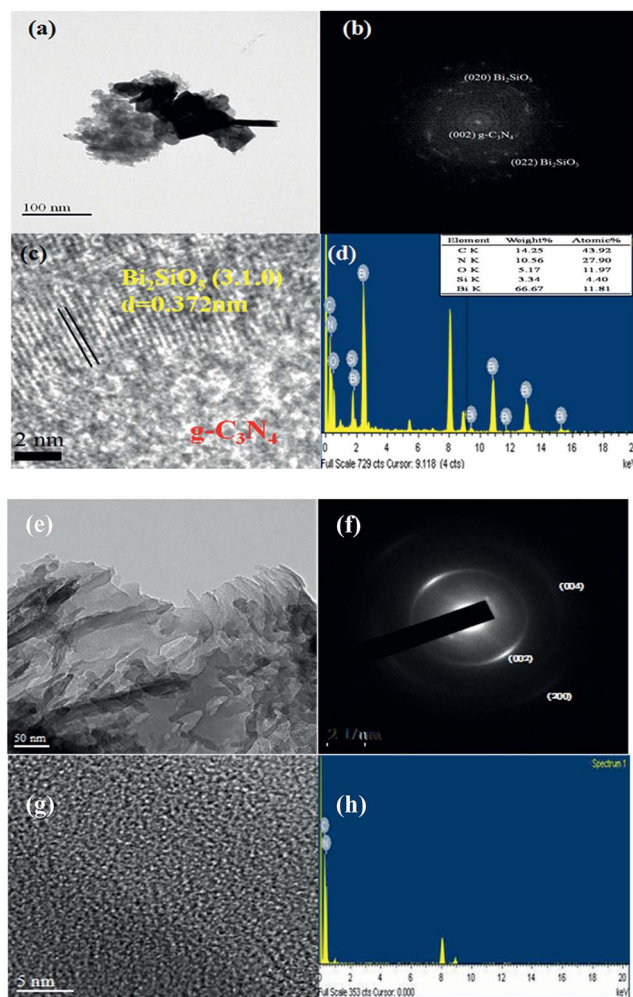


Fig. 2 FE-TEM and EDS of (a)–(d) as-prepared 10 wt% Bi₂SiO₅/g-C₃N₄ and (e)–(h) pure g-C₃N₄.

layers, consistent with the TEM observations. In addition, the EDS spectrum shows that the sample contains the elements of Bi, Si, O, C, and N. The HRTEM image shows that one set of different lattice images is found with a *d*-spacing of 0.372 nm, corresponding to the (310) plane of Bi₂SiO₅, which is in good agreement with the XRD results. The results suggest that the Bi₂SiO₅/g-C₃N₄ phases have been formed in the composites, which is favorable for the separation of photoinduced carriers, yielding high photocatalytic activities. Fig. 2(e)–(h) show the irregular edge morphology, which is consistent with the reference sample.⁶⁷ The results suggest that the g-C₃N₄ phases have been formed.

FT-IR spectra are shown in Fig. 3. Based on previously reports,^{68,69} the peaks located at around 430 cm⁻¹, 570 cm⁻¹, 857 cm⁻¹, 946 cm⁻¹ and 1030 cm⁻¹ belong to the stretching vibration mode of Bi–O bonds, SiO₄⁴⁻ groups, Bi–O–Si bonds, isolated SiO₅⁶⁻ groups and Si–O bonds, respectively. Relative to pure g-C₃N₄, the peaks at 1252, 1326, 1420, 1572, and 1640 cm⁻¹ correspond to the typical stretching modes of the CN heterocycles.^{70,71} In addition, the characteristic breathing mode of the triazine units at 811 cm⁻¹ is observed.⁷² These results agree with those of the XRD and TEM experiments.

The proposed processes for the formation of Bi₂SiO₅/g-C₃N₄ composites are described in eqn (1)–(4). The results demonstrate a series of changes in the compounds prepared under different hydrothermal conditions, described as Bi₂Si₃O₉ → Bi₄Si₃O₁₂ → Bi₂SiO₅. By controlling the pH of the hydrothermal reaction, different compositions of bismuth silicates are obtained as follows:

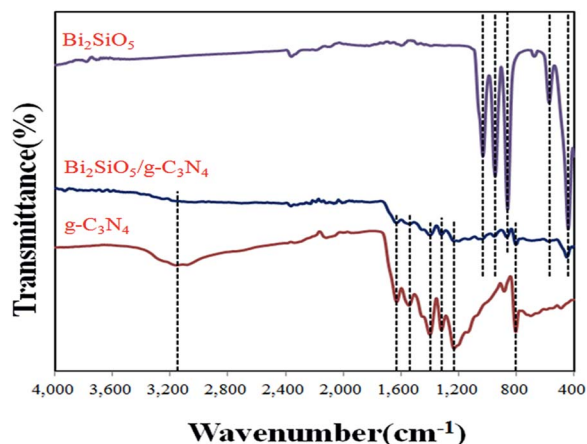
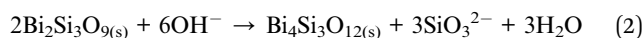
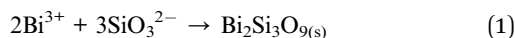


Fig. 3 FTIR spectra of as-prepared Bi₂SiO₅, g-C₃N₄, and 10 wt% Bi₂SiO₅/g-C₃N₄.

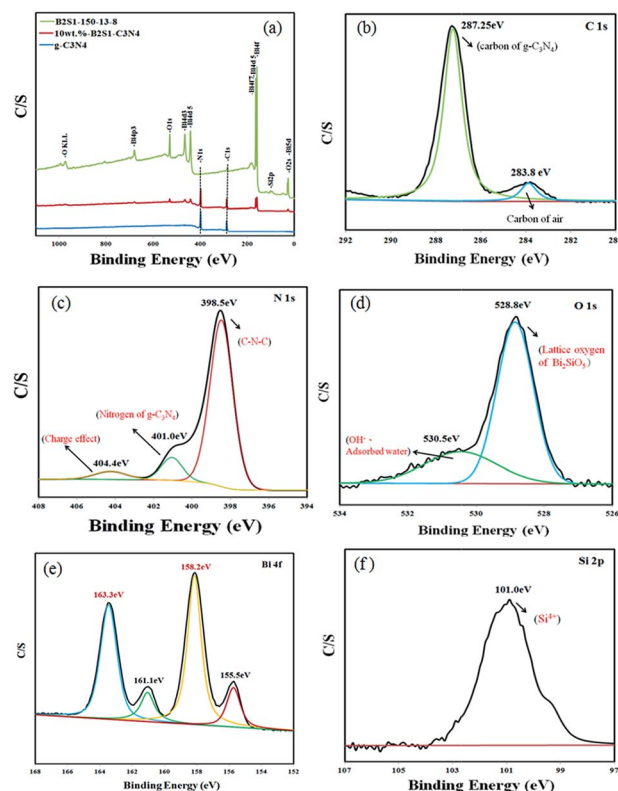


Fig. 4 High resolution XPS spectra of the Bi₂SiO₅, g-C₃N₄ and 10 wt% Bi₂SiO₅/g-C₃N₄ composite: (a) total survey, (b) C 1s, (c) N 1s, (d) O 1s, (e) Bi 4f, and (f) Si 2p.

3.1.2. X-ray photoelectron spectroscopy analysis. Fig. 4 presents the C 1s, N 1s, O 1s, Bi 4f, and Si 2p XPS spectra of the Bi₂SiO₅/g-C₃N₄ composites. Observation of the transition peaks involving the O 1s, C 1s, N 1s, Bi 4f, and Si 2p orbitals identifies that the catalysts are composed of Bi, Si, O, C, and N. Fig. 4(b) shows the high resolution C 1s spectrum of Bi₂SiO₅/g-C₃N₄ composites. There are mainly two carbon species displayed in the C 1s spectra. One peak (283.8 eV) is attributed to the sp² C–C bond, and the other (287.25 eV), to the sp²-hybridized carbon in the N-containing aromatic ring (N–C=N). The latter is indicated as the major carbon species in polymeric g-C₃N₄.⁷¹ In Fig. 4(c), three peaks are deconvoluted for the N 1s spectra. The highest peak centering at 398.5 eV is assigned to the sp²-hybridized nitrogen involved in triazine rings (C–N=C), whereas the peak at 401.0 eV corresponds to the tertiary nitrogen N–(C)₃ groups. Both of them, together with sp²-hybridized carbon (N–C=N, 287.9 eV), compose the heptazine heterocyclic ring units, constructing the basic substructure units of g-C₃N₄ polymers. The weak peak at 404.4 eV is attributed to charging effects or positive charge localization in the heterocycles.⁷² The asymmetric O 1s peak shown in Fig. 4(d) can be split by using the XPS peak-fitting program. The peak at 530.5 eV is assigned to the external –OH groups or the water molecules adsorbed on the surface, and the other O 1s peak appearing at 528.8 eV corresponds to lattice oxygen atoms in the Bi₂SiO₅.⁷³ The characteristic binding energy value of 158.2 eV for Bi 4f_{7/2} (Fig. 4(e)) shows a trivalent oxidation state for bismuth.

An additional spin-orbit doublet with the binding energy of 155.5 eV for Bi 4f_{7/2} is also revealed in all samples, suggesting that certain parts of bismuth exist in the (+3 - x) valence state. This shows that the trivalent bismuth is partially reduced to the lower valence state by the hydrothermal method. A similar chemical shift of approximately 2.7 eV for Bi 4f_{7/2} was also published by Liao *et al.*⁷⁴ They summarized that the Bi^(+3-x) formal oxidation state could most probably be ascribed to the sub-stoichiometric forms of Bi within the Bi₂O₂ layer, and the formation of the low oxidation state results in oxygen vacancies in the crystal lattice. However, it is supposed in this study that the Bi^(+3-x) formal oxidation state could most likely be ascribed to the sub-stoichiometric forms of Bi at the outer sites of the particles, and the formation of the low oxidation state results in oxygen vacancies in the crystal surface, revealing that the main chemical states of the bismuth element in the samples are not trivalent. From Fig. 4(f), the binding energy of 101.0 eV is attributed to Si 2p_{3/2}, which points to Si in the tetravalent oxidation state.

3.1.3. Morphological structure and composition. Fig. 5 shows the FESEM images of the Bi₂SiO₅, g-C₃N₄, Bi₂SiO₅/g-C₃N₄ composites at high magnification. The Bi₂SiO₅, g-C₃N₄, and Bi₂SiO₅/g-C₃N₄ samples show square-plates, nanosheets, and bulk morphology, respectively. The SEM-EDS and TEM-EDS results demonstrate that the main elements within these samples are carbon, nitrogen, oxygen, silicon, and bismuth, shown in Fig. 2 and 5. Based on the above results, Bi₂SiO₅/g-

C₃N₄ composites could be selectively synthesized through a controlled hydrothermal method.

3.1.4. Optical absorption properties. As shown in Fig. 6 for DR-UV of the Bi₂SiO₅/g-C₃N₄ composites, the absorption edge of the pure g-C₃N₄ is at about 482.5 nm, which originates from its band gap of 2.38 eV and is consistent with the reported results.⁷⁴ Pure g-C₃N₄ and Bi₂SiO₅ absorb only a small amount of visible light. The E_g value of Bi₂SiO₅/g-C₃N₄ was determined from a plot of $(\alpha h\nu)^{1/2}$ vs. energy ($h\nu$), which was calculated as 2.46 eV.

3.1.5. BET and adsorption-desorption isotherm. The 10 wt% Bi₂SiO₅/g-C₃N₄ composite has the middle S_{BET} value and the highest pore volume (Table 1). However, the results from Table 2 show that the 10 wt% Bi₂SiO₅/g-C₃N₄ sample, which shows the middle S_{BET} value, does represent the highest photocatalytic activity ($k = 1.1257 \times 10^{-1} \text{ h}^{-1}$) among the samples, suggesting that the changes in the photocatalytic activity result from Bi₂SiO₅/g-C₃N₄ composites.

Fig. 7 shows the nitrogen adsorption-desorption isotherm curves of Bi₂SiO₅, g-C₃N₄ and Bi₂SiO₅/g-C₃N₄. The isotherms of g-C₃N₄ are close to Type IV with a hysteresis loop at a high relative pressure between 0.6 and 1.0.⁷⁵ The isotherms of Bi₂SiO₅ and Bi₂SiO₅/g-C₃N₄ are close to Type III, with hysteresis loops at a high relative pressure between 0.6 and 1.0. The shape of the hysteresis loop is close to Type H3, suggesting the existence of slit-like pores, generally formed by the aggregation of plate-like particles, which is consistent with the self-assembled

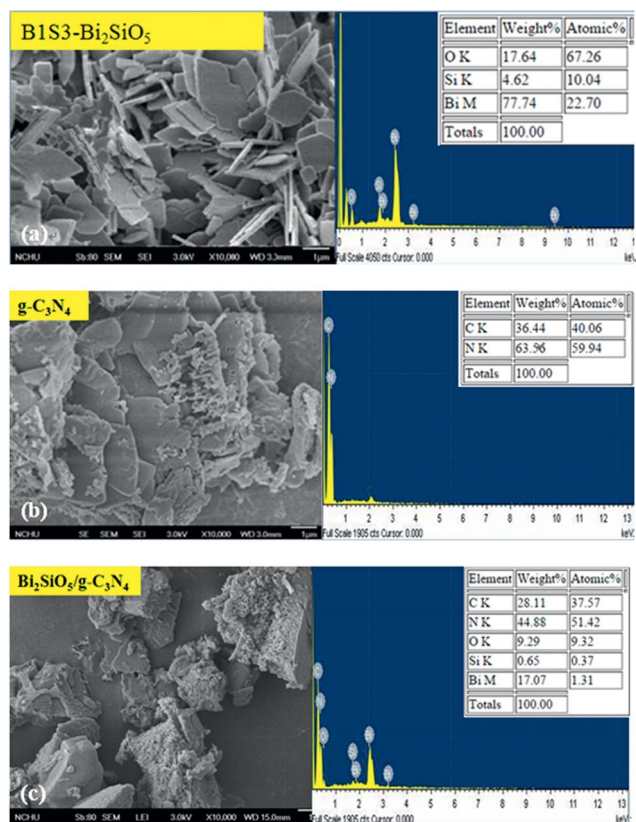


Fig. 5 FE-SEM and EDS of the as-prepared (a) Bi₂SiO₅, (b) g-C₃N₄, and (c) 10 wt% Bi₂SiO₅/g-C₃N₄.

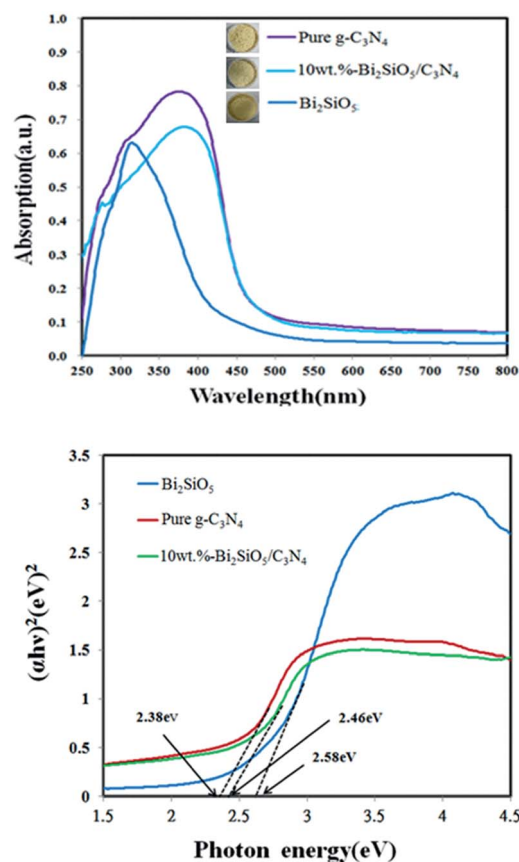


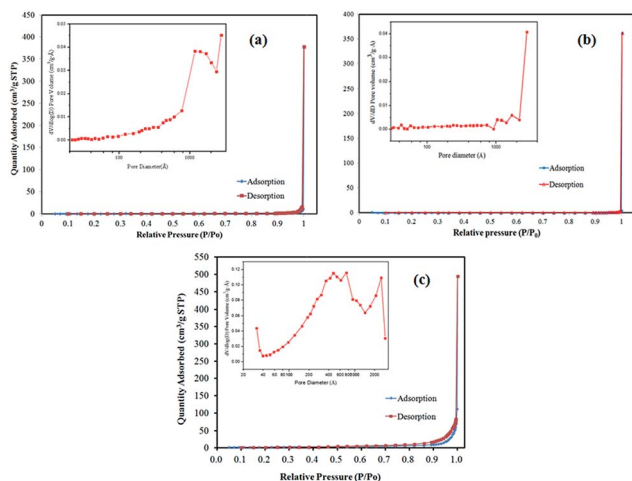
Fig. 6 DRS patterns of the as-prepared Bi₂SiO₅, g-C₃N₄, and 10 wt% Bi₂SiO₅/g-C₃N₄.

Table 1 Physical and chemical properties of the as-prepared samples

Sample	Specific surface area ($\text{m}^2 \text{g}^{-1}$)	Pore volume ($\text{cm}^3 \text{g}^{-1}$)	Pore diameter (nm)
Bi_2SiO_5	1.54	0.012	37.60
$\text{g-C}_3\text{N}_4$	17.60	0.1975	28.54
10 wt% $\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$	8.8108	0.112	37.85

Table 2 The pseudo-first-order rate constants for the degradation of CV with $\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$ photocatalysts under visible light irradiation

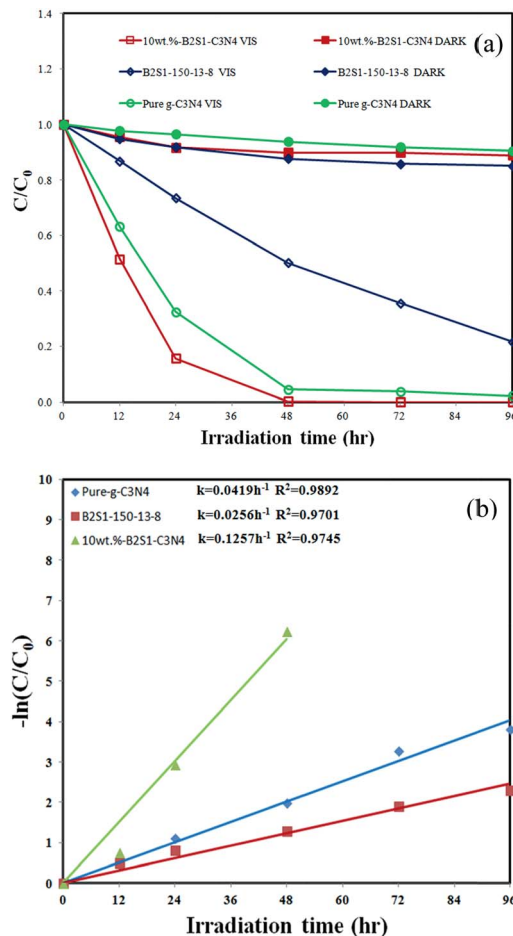
	k (h^{-1})	R^2
Pure- $\text{g-C}_3\text{N}_4$	0.0419	0.9892
1 wt% $\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$	0.0814	0.9794
5 wt% $\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$	0.0857	0.9580
7 wt% $\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$	0.1104	0.9549
10 wt% $\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$	0.1257	0.9745
20 wt% $\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$	0.0360	0.9997
50 wt% $\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$	0.0332	0.9783
Bi_2SiO_5	0.0256	0.9701

Fig. 7 N_2 adsorption–desorption isotherms and pore size distribution of (a) Bi_2SiO_5 , (b) $\text{g-C}_3\text{N}_4$, and (c) 10 wt% $\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$.

nanoplate-like morphology of the samples. This result is consistent with the image results of FE-SEM and TEM, showing that self-assembled nanosheets or nanoplates result in the formation of hierarchical architectures.

3.2. Photocatalytic activity

The degradation efficiency as a function of reaction time is illustrated in Fig. 8(a). The removal efficiency is significantly enhanced in the presence of 10 wt% $\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$. After irradiation for 48 h, the 10 wt% $\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$ exhibits superior photocatalytic performance, with CV removal efficiency of up to 99%. To further understand the reaction kinetics of CV degradation, the apparent pseudo-first-order model⁷⁶ expressed by

Fig. 8 Photodegradation of CV as a function of irradiation time, using the as-prepared Bi_2SiO_5 , $\text{g-C}_3\text{N}_4$, and 10 wt% $\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$.

$\ln(C_0/C) = kt$ equation was applied in the experiments. Via the first-order linear fit of the data shown in Fig. 8(b) and Table 2, the k value of 10 wt% $\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$ was obtained as the maximum degradation rate of $1.257 \times 10^{-1} \text{h}^{-1}$ using the first-order linear fit of the data, which is much higher than that of the other composites; the 10 wt% $\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$ composite is a much more effective photocatalyst than the others synthesized in this study. Comparison of rate constants of different photocatalysts is shown in Table 2. The order of the rate constants is 10 wt% $\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4 > 7 \text{ wt% } \text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4 > 5 \text{ wt% } \text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4 > 1 \text{ wt% } \text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4 > 20 \text{ wt% } \text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4 > 50 \text{ wt% } \text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$. The photocatalytic activity of the 10 wt% $\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$ heterojunctions reached the maximum rate constant of $1.257 \times 10^{-1} \text{h}^{-1}$, which is 5 times higher than that of Bi_2SiO_5 and 3 times higher than that of $\text{g-C}_3\text{N}_4$. Thus, the $\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$ composites may also play a role in enhancing the photocatalytic activity.

The durability of the 10 wt% $\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$ composite was evaluated by recycling the used catalyst. After each cycle, the catalyst was collected by centrifugation. No apparent loss was observed in the photocatalytic activity when CV was removed in the 3rd cycle; even during the fifth run, the decline in the photocatalytic activity was 3.5% (Fig. 9(a)). The used 10 wt%

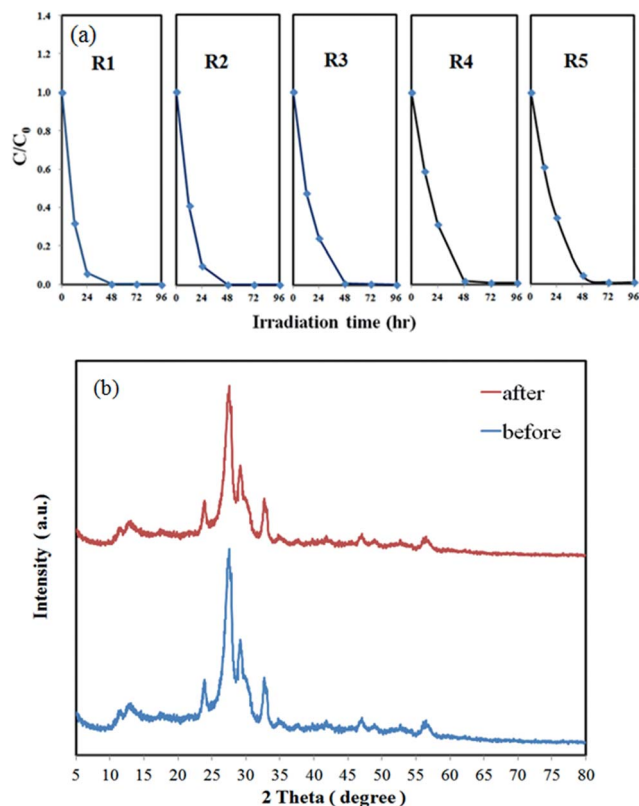


Fig. 9 (a) Cycling runs in the photocatalytic degradation of CV in the presence of 10 wt% $\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$, (b) XRD of the sample powder before and after the degradation reaction.

$\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$ composite was also examined by XRD and no detectable difference was observed between the as-prepared and the used samples (Fig. 9(b)); hence, the 10 wt% $\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$ composite has good photostability.

As is known, the photocatalysts become excited and generate electron-hole pairs directly after illumination in the photocatalytic process. Moreover, the photocatalytic performance mainly depends on the recombination rate or the lifetime of the

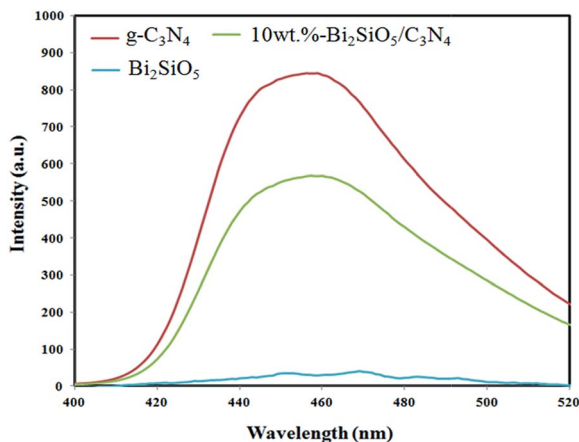


Fig. 10 PL spectra of as-prepared Bi_2SiO_5 , $\text{g-C}_3\text{N}_4$, and 10 wt% $\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$.

photo-generated electron-hole pairs. The faster recombination occurs, the less time is required for the chemical reactions. Therefore, PL spectra are utilized for investigating the recombination rates of the photogenerated electron-hole pairs.⁷⁷ To investigate the separation capacity of the photogenerated carriers in the heterostructures, the PL spectra of $\text{g-C}_3\text{N}_4$, Bi_2SiO_5 , and 10 wt% $\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$ were obtained and the results are shown in Fig. 10. A strong emission peak around 458 nm appears for the as-prepared samples, which could have been derived from the direct electron-hole recombination of band transitions. However, the characteristic emission peak of lowest intensity, around 458 nm for the 10 wt% $\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$, indicates that the recombination of photogenerated charge carriers is greatly inhibited. The efficient separation of charge could increase the lifetime of charge carriers and enhance the efficiency of interfacial charge transfer to the adsorbed substrates, thus improving the photocatalytic activity.^{78,79} The lowest relative PL intensities of 10 wt% $\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$ composites, as shown in Fig. 10, suggest that they possess the lowest recombination rate of electron-hole pairs, resulting in their higher photocatalytic activity, as shown in Fig. 8(b). The PL results confirm the importance of the heterojunction in hindering the recombination of electrons and holes and explain the reason for the increasing photocatalytic performance of 10 wt% $\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$ composites.

It can be assumed that the enhanced photocatalytic activities of 10 wt% $\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$ composites could be ascribed to the formation of the heterojunction. In the absence of photocatalysts, CV could not be degraded under visible-light irradiation. The superior photocatalytic ability of the 10 wt% $\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$ may be ascribed to its efficient utilization of visible light and the high separation efficiency of the electron-hole pairs within its composites.

As shown in Table 3, graphitic carbon nitride composites have received remarkable interest in recent years because of their suitable band gaps, stability, and relatively superior photocatalytic activities. It is found that the graphitic carbon nitride composites show higher photocatalytic activities than $\text{g-C}_3\text{N}_4$ for the photocatalytic degradation of rhodamine B (or methyl blue, methyl orange, crystal violet).⁸⁰⁻⁸⁹

3.3. Photodegradation mechanisms of CV

In general, three possible reaction pathways are assumed to be involved in the photodegradation of organic compounds by a photocatalyst: (i) photocatalysis, (ii) photolysis, and (iii) dye photosensitization.⁹⁰ In the photolysis process, a photoinduced electron on the induced compound directly reacts with O_2 to produce $^1\text{O}_2$, which acts as an oxidant for the photolysis of the compound.⁹¹ In the experiments, CV degradation induced by photolysis under visible light in a blank experiment was not observable; CV is a structure-stable dye and the decomposition by the photolysis mechanism is negligible.

As people may know, various primary active species, such as HO^\cdot , h^\cdot , O_2^\cdot , H^\cdot and $^1\text{O}_2$, could be generated during photocatalytic degradation reactions in the UV-vis/semiconductor systems.^{91,92} Dimitrijevic *et al.*⁹² proposed that water,

Table 3 Photocatalytic properties of composite photocatalysts under visible light irradiation

Composite photocatalyst	Mass fraction of g-C ₃ N ₄ (wt%)	Dye	Photocatalytic activity	Reference photocatalyst/ photocatalytic activity	Enhancement factor	Reference
BiOI/g-C ₃ N ₄	15	Rhodamine B	90% decomposition in 30 min	BiOI: 26.3% for rhodamine B	3.8	80
Bi ₅ O ₇ I/g-C ₃ N ₄	30	Rhodamine B	90% decomposition in 2 h	g-C ₃ N ₄ : 6.5% Bi ₅ O ₇ I: 34.5%	15.3 2.9	81
SrFeO _{3-x} /g-C ₃ N ₄	96	Crystal violet	90% decomposition in 24 h	g-C ₃ N ₄ : 20.8%	4.8	82
WO ₃ /g-C ₃ N ₄	90.3	Methylene blue	97% decomposition in 2 h	g-C ₃ N ₄ : 81%, 3 h WO ₃ : 73%, 3 h	1.2 1.3	83
CeO ₂ /g-C ₃ N ₄	87	Methylene blue	95% decomposition in 2 h	g-C ₃ N ₄ : 75%, 3 h CeO ₂ : 28%, 3 h	1.3 3.4	84
Bi ₂ WO ₆ /g-C ₃ N ₄	50	Methyl orange	93% decomposition in 2 h	g-C ₃ N ₄ : 31% Bi ₂ WO ₆ : 0.6%	3 155	85
Ag ₃ VO ₄ /g-C ₃ N ₄	40	Basic fuchsin	95% decomposition in 2.5 h	g-C ₃ N ₄ : 15% Ag ₃ VO ₄ : 30%	6.3 3.2	86
BiOBr/g-C ₃ N ₄	50	Rhodamine B	93% decomposition in 30 min	g-C ₃ N ₄ : 15% BiOBr: 35%	6.3 2.7	87
Ag/g-C ₃ N ₄	Ag: 0.1 g	Methyl orange	74% decomposition	g-C ₃ N ₄ : 70%	1.3	88
Ag/AgBr/g-C ₃ N ₄	5	Methyl orange	95.3% decomposition in 30 min	g-C ₃ N ₄ : 2.5% Ag/AgBr: 62.3%	38.1 1.5	89

dissociated both on the surface of TiO₂ and in subsequent molecular layers, has a three-fold role as follows: (i) the stabilization of charges, preventing electron-hole recombination, (ii) electron acceptor, involving the formation of H atoms in a reaction of photo-generated electrons with protons on the surface to give -OH₂⁺, and (iii) electron donor, water reacts with photo-generated holes to give ·OH radicals.

Ma *et al.* revealed that O₂^{·-} was the main active species for NO oxidation to NO₃⁻ with TO₂/g-C₃N₄ under visible and UV light.⁹³ Cheng's group illustrated a typical Z-scheme photocatalyst being favorable for the production of O₂^{·-} and ·OH reactive species.⁹⁴ Jiang *et al.* revealed that the photogenerated h⁺ and O₂^{·-} were the main oxidative species for the degradation of methyl orange.⁹⁵ The generation of O₂^{·-} could not only

inhibit the recombination of photoinduced charge carriers, but also benefit the de-chlorination of chlorinated phenol derivatives. The hydroxyl radical HO· might only be obtained *via* an e⁻ → O₂^{·-} → H₂O₂ → ·OH route. Moreover, ·OH radicals were obtained by multistep reduction O₂^{·-} in the system.⁷⁸ Hong *et al.* reported that O₂^{·-} played a major role in the V₂O₅/g-C₃N₄ heterojunctions photocatalytic reactions of rhodamine B and tetracycline, rather than the ·OH radical.⁹⁶ According to earlier studies,⁹⁴ the photocatalytic process was mainly governed by O₂^{·-}, rather than by ·OH, e⁻ or h⁺. The CV photodegradation by BiO_mX_n/BiO_pX_q (X, Y = Cl, Br, I) under visible light was dominated by O₂^{·-} oxidation, with O₂^{·-} being the main active species and ·OH and h⁺ being the minor active species.^{78,97} On the basis of the references presented above, it is proposed that the probability of forming ·OH should be much lower than that for O₂^{·-}; however, ·OH is an extremely strong and nonselective oxidant, which leads to the partial or complete mineralization of several organic chemicals.

In order to evaluate the effect of the active species during the photocatalytic processes, a series of quenchers was used to scavenge the relevant active species. As shown in Fig. 11, the photocatalytic degradation of CV was slightly affected by the addition of AO, IPA and SA, while the degradation efficiency of BQ quenching evidently decreases, compared with that of no-quenching, indicating that ·OH, h⁺ and ¹O₂ are the minor active species, whereas O₂^{·-} is the major active species in the process of the photocatalytic degradation of CV.

In order to re-evaluate the effect of the active species during the photocatalytic reaction, EPR measurements were used to scavenge the relevant active species. From Fig. 12, not only were the six characteristic peaks of the DMPO-O₂^{·-} adducts observed, but the four characteristic peaks of DMPO-·OH adducts (1 : 2 : 2 : 1 quartet pattern) were also observed upon irradiation of the 10 wt% Bi₂SiO₅/g-C₃N₄ composite dispersion with visible light. Fig. 12(a) and (b) show that no EPR signal is

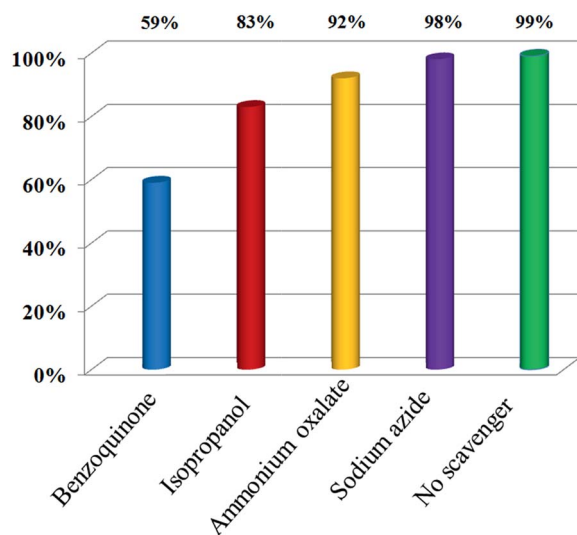


Fig. 11 Trapping of active species during the photocatalytic reaction using 10 wt% Bi₂SiO₅/g-C₃N₄.

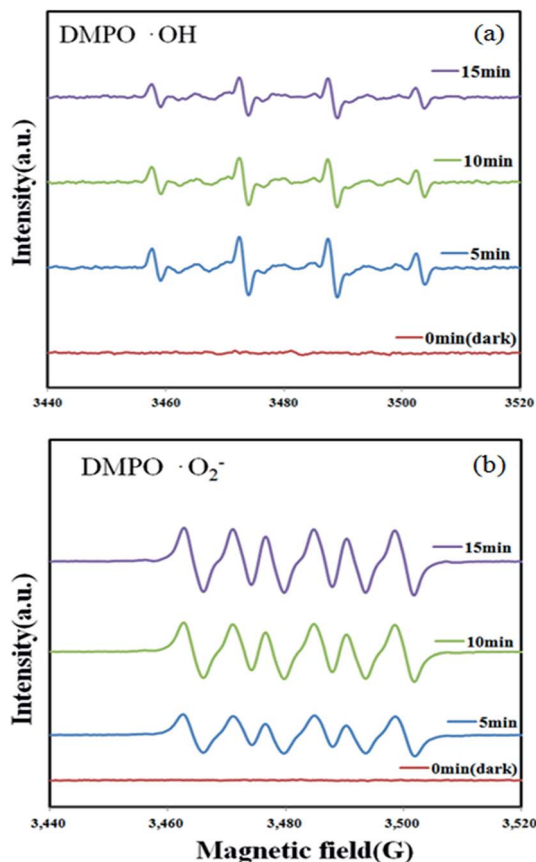


Fig. 12 ESR spectra of (a) DMPO- $\cdot\text{OH}$ and (b) DMPO- $\text{O}_2^{\cdot-}$ using 10 wt% $\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$ dispersion in methanol solution under visible light irradiation.

observed when the reaction is performed in the dark, while the signals with intensities corresponding to the characteristic peaks of DMPO- $\cdot\text{OH}$ and DMPO- $\text{O}_2^{\cdot-}$ adducts⁹⁸ are observed during the reaction process under visible light irradiation, and the intensity gradually increases with prolonged reaction time, suggesting that $\text{O}_2^{\cdot-}$ and $\cdot\text{OH}$ are formed as active species in the presence of 10 wt% $\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$ composites and oxygen under visible light irradiation. Therefore, the quenching effects of different scavengers and EPR show that the reactive $\text{O}_2^{\cdot-}$ plays the major role and $\cdot\text{OH}$ and h^+ play minor roles in the photocatalytic degradation of CV.

Fan *et al.* revealed⁹⁹ that Pt- TiO_2 gathered less negative species on catalyst surfaces, which decreased reaction rates, than pure TiO_2 did in an acidic environment. The $\cdot\text{OH}$ radical was produced subsequently, as also expressed in eqn (5)–(10).

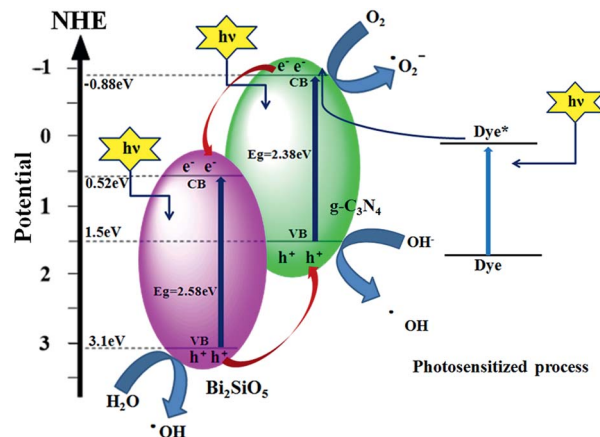
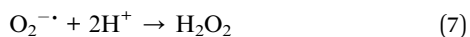
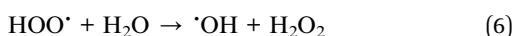
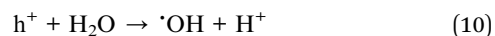
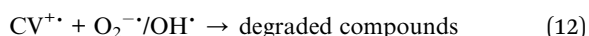


Fig. 13 The band structure diagram of $\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$ and the possible charge separation processes.



On the basis of the above experimental results, a proposed mechanism of degradation is illustrated in Fig. 13. Once the electron reaches the conduction band of Bi_2SiO_5 , it induces the formation of active oxygen species, which cause the degradation of CV. It is clear that except for the photodegradation of CV by the route of $\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$ -mediated and photosensitized processes, another type of photocatalytic route accounts for the enhanced photocatalytic activity. In Fig. 13, both the photosensitized and photocatalytic processes proceed concurrently. However, in photosensitized and photocatalytic processes, $\text{O}_2^{\cdot-}$ radicals are generated by the reaction of photogenerated and photosensitized electrons with oxygen gas on the photocatalyst surface, and $\cdot\text{OH}$ radicals are also generated by the reaction of $\text{O}_2^{\cdot-}$ radicals with H^+ ions, and holes h^+ with OH^- ions (or H_2O). The $\cdot\text{OH}$ radical is produced subsequently, as expressed in eqn (5)–(10). These cycles continuously occur when the system is exposed to visible-light irradiation,⁷⁸ and after several cycles of photo-oxidation, the degradation of CV by the produced oxidant species can be expressed by eqn (11) and (12):



In a visible-light-induced semiconductor system, hydroxylated compounds were also identified for the photocatalytic degradation of CV.^{78,97} In earlier reports,^{17,99–102} the *N*-dealkylation processes were preceded by the generation of a nitrogen-centered radical, and the destruction of the dye chromophore structure was preceded by the formation of a carbon-centered radical in the photocatalytic degradation of CV dye under UV or visible light irradiation. The reaction mechanisms for $\text{Bi}_2\text{SiO}_5/\text{g-C}_3\text{N}_4$ -mediated photocatalytic processes proposed in this research should offer some insight for application to the decoloration of dyes.

The details of the separation and identification of intermediates have been provided in Fig. S1–S4 and Table S1 of ESI.†

The details of the mechanisms of photocatalytic degradation have been shown in Fig. S5–S7 of the ESI.†

4. Conclusions

This is the first report on the synthesis of Bi₂SiO₅/g-C₃N₄ composites by a template-free hydrothermal method. The removal efficiency is significantly enhanced in the presence of 10 wt% Bi₂SiO₅/g-C₃N₄. The increased photocatalytic activities of Bi₂SiO₅/g-C₃N₄ could be attributed to the formation of the heterojunction between Bi₂SiO₅ and g-C₃N₄, which effectively suppresses the recombination of photo-generated electron–hole pairs. It can be concluded that the enhanced photocatalytic activities of Bi₂SiO₅/g-C₃N₄ materials could be due to the formation of the heterojunction. The quenching effects and EPR results illustrate that the reactive O₂^{•−} plays the major role and [•]OH, h⁺ and ¹O₂ play minor roles in the CV degradation. This work is useful for the synthesis of Bi₂SiO₅/g-C₃N₄ and the photocatalytic degradation of the CV for future applications in environmental pollution and control.

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